NSN 5961-01-083-2910

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-083-2910 **Inclosure Material:** Plastic **Overall Length:** Between 0.270 inches and 0.410 inches **Overall Height:** Between 0.130 inches and 0.190 inches Overall Width: Between 0.190 inches and 0.230 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 12.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 100.00 milliamperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6599 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No